

## **INCHANGE SEMICONDUCTOR**

## **isc Silicon NPN Power Transistor**

# 2SC4429

### DESCRIPTION

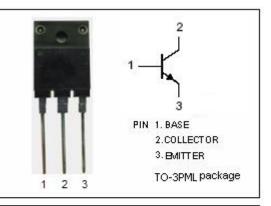
- High Breakdown Voltage-
- : V<sub>(BR)CEO</sub>= 800V(Min)
- · Fast Switching speed
- Wide Area of Safe Operation
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

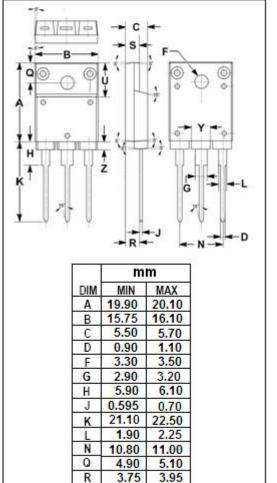
### **APPLICATIONS**

Designed for switching regulator Applications

### ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

| SYMBOL           | PARAMETER                                       | VALUE   | UNIT |  |
|------------------|---|---------|------|--|
| V <sub>CBO</sub> | Collector-Base Voltage                          | 1100    | v    |  |
| V <sub>CEO</sub> | Collector-Emitter Voltage                       | 800     | V    |  |
| V <sub>EBO</sub> | Emitter-Base Voltage                            | 7       | V    |  |
| lc               | Collector Current-Continuous                    | 8       | А    |  |
| I <sub>CP</sub>  | Collector Current-Pulse                         | 25      | А    |  |
| I <sub>B</sub>   | Base Current-Continuous                         | 4       | A    |  |
| Pc               | Collector Power Dissipation @ $T_c=25^{\circ}C$ | 60      | w    |  |
|                  | Collector Power Dissipation @ $T_a=25^{\circ}C$ | 3       |      |  |
| TJ               | Junction Temperature                            | 150     | °C   |  |
| T <sub>stg</sub> | Storage Temperature Range                       | -55~150 | °C   |  |





isc website: <u>www.iscsemi.com</u>

<sup>1</sup> *isc* & *iscsemi* is registered trademark

s

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Y

Ζ

3.20

9.90

4.20

1.90

3.60

10.10

4.90

2.10



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### **ELECTRICAL CHARACTERISTICS**

#### T<sub>c</sub>=25℃ unless otherwise specified

| SYMBOL               | PARAMETER                            | CONDITIONS                                  | MIN  | TYP. | МАХ | UNIT |
|----------------------|--------------------------------------|---|------|------|-----|------|
| V <sub>(BR)CEO</sub> | Collector-Emitter Breakdown Voltage  | I <sub>C</sub> =5mA; I <sub>B</sub> = 0     | 800  |      |     | V    |
| V <sub>(BR)CBO</sub> | Collector-Base Breakdown Voltage     | I <sub>C</sub> =1mA; I <sub>E</sub> =0      | 1100 |      |     | V    |
| V <sub>(BR)EBO</sub> | Emitter-Base Breakdown Voltage       | I <sub>E</sub> =1mA; I <sub>C</sub> =0      | 7    |      |     | V    |
| V <sub>CE(sat)</sub> | Collector-Emitter Saturation Voltage | I <sub>C</sub> = 4A; I <sub>B</sub> = 0.8A  |      |      | 2.0 | V    |
| V <sub>BE(sat)</sub> | Base-Emitter Saturation Voltage      | I <sub>C</sub> = 4A; I <sub>B</sub> = 0.8A  |      |      | 1.5 | V    |
| Ісво                 | Collector Cutoff Current             | V <sub>CB</sub> = 800V; I <sub>E</sub> = 0  |      |      | 10  | μA   |
| I <sub>EBO</sub>     | Emitter Cutoff Current               | V <sub>EB</sub> = 5V; I <sub>C</sub> = 0    |      |      | 10  | μA   |
| h <sub>FE-1</sub>    | DC Current Gain                      | I <sub>C</sub> =0.6A ; V <sub>CE</sub> = 5V | 10   |      | 40  |      |
| hfe-2                | DC Current Gain                      | Ic= 3A ; Vc== 5V                            | 8    |      |     |      |

#### h<sub>FE-1</sub> Classifications

| К     | L     | м     |
|-------|-------|-------|
| 10-20 | 15-30 | 20-40 |

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